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FAIRCHILD

SEMICONDUCTOR

MM74HCT04 Hex Inverter

General Description

The MM74HCT04 is a logic function fabricated by using advanced silicon-gate CMOS technology which provides the inherent benefits of CMOS - low quiescent power and wide power supply range. This device is input and output characteristic as well as pin-out compatible with standard 74LS logic families. The MM74HCT04, triple buffered, hex inverters, features low power dissipation and fast switching times. All inputs are protected from static discharge by internal diodes to V_{CC} and ground.

MM74HCT devices are intended to interface between TTL and NMOS components and standard CMOS devices. These parts are also plug-in replacements for LS-TTL devices and can be used to reduce power consumption in existing designs.

Features

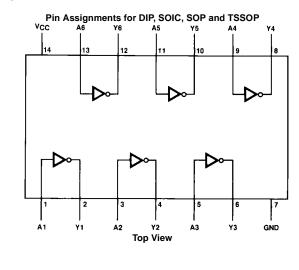
- TTL, LS pin-out and threshold compatible
- Fast switching: t_{PLH}, t_{PHL}=12 ns (typ)
- \blacksquare Low power: 10 μW at DC, 3.7 mW at 5 MHz
- High fanout: ≥ 10 LS loads
- Inverting, triple buffered

Ordering Code:

Order Number	Package Number	Package Description
MM74HCT04M	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow
MM74HCT04SJ	M14D	Pb-Free 14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
MM74HCT04MTC	MTC14	14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
MM74HCT04N	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
MM74HCT04N_NL	N14A	Pb-Free 14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code. Pb-Free package per JEDEC J-STD-020B.

Connection Diagram



Absolute Maximum Ratings(Note 1) (Note 2)

Supply Voltage (V _{CC})	-0.5 to +7.0V
DC Input Voltage (V _{IN})	–1.5 to V_{CC} +1.5V
DC Output Voltage (V _{OUT})	–0.5 to V_{CC} +0.5V
Clamp Diode Current (I _{IK} , I _{OK})	±20 mA
DC Output Current, per pin (I _{OUT})	±25 mA
DC V _{CC} or GND Current, per pin (I _{CC})	±50 mA
Storage Temperature Range (T _{STG})	-65°C to +150°C
Power Dissipation (P _D)	
(Note 3)	600 mW
S.O. Package only	500 mW
Lead Temperature (T _L)	
(Soldering 10 seconds)	260°C

Recommended Operating Conditions

	Min	Max	Units	
Supply Voltage (V _{CC})	4.5	5.5	V	
DC Input or Output Voltage				
(V _{IN} , V _{OUT})	0	V _{CC}	V	
Operating Temperature Range (T_A)	-40	+85	°C	
Input Rise or Fall Times				
(t _r , t _f)		500	ns	
Note 1: Absolute Maximum Ratings are those age to the device may occur.	values b	eyond whi	ch dam-	

Note 2: Unless otherwise specified all voltages are referenced to ground. Note 3: Power Dissipation temperature derating — plastic "N" package: – 12 mW/°C from 65°C to 85°C.

DC Electrical Characteristics

$V_{CC} = 5V \pm 10\%$ (unless otherwise specified)

Symbol	Parameter	Conditions	$T_A = 25^{\circ}C$		$T_A = -40$ to $85^{\circ}C$	$T_A = -55$ to $125^{\circ}C$	Units
Symbol	Faralleler	Conditions	Тур		Guaranteed I	Units	
VIH	Minimum HIGH Level			2.0	2.0	2.0	V
	Input Voltage						
V _{IL}	Maximum LOW Level			0.8	0.8	0.8	V
	Input Voltage						
V _{OH}	Minimum HIGH Level	$V_{IN} = V_{IL}$					
	Output Voltage	$ I_{OUT} = 20 \ \mu A$	V _{CC}	$V_{CC} - 0.1$	$V_{CC} - 0.1$	$V_{CC} - 0.1$	V
		$ I_{OUT} = 4.0 \text{ mA}, V_{CC} = 4.5 \text{V}$	4.2	3.98	3.84	3.7	V
		$ I_{OUT} = 4.8$ mA, $V_{CC} = 5.5$ V	5.2	4.98	4.84	4.7	V
V _{OL}	Maximum LOW Level	$V_{IN} = V_{IH}$					
	Voltage	$ I_{OUT} = 20 \ \mu A$	0	0.1	0.1	0.1	V
		$ I_{OUT} = 4.0 \text{ mA}, V_{CC} = 4.5 \text{V}$	0.2	0.26	0.33	0.4	V
		$ I_{OUT} = 4.8$ mA, $V_{CC} = 5.5$ V	0.2	0.26	0.33	0.4	V
I _{IN}	Maximum Input	$V_{IN} = V_{CC}$ or GND,		±0.1	±1.0	±1.0	μA
	Current	V _{IH} or V _{IL}					
I _{CC}	Maximum Quiescent	$V_{IN} = V_{CC}$ or GND		2.0	20	40	μA
	Supply Current	$I_{OUT} = 0 \ \mu A$					
		V _{IN} = 2.4V or 0.5V (Note 4)		0.3	0.4	0.5	mA

Note 4: This is measured per input with all other inputs held at V_{CC} or ground.

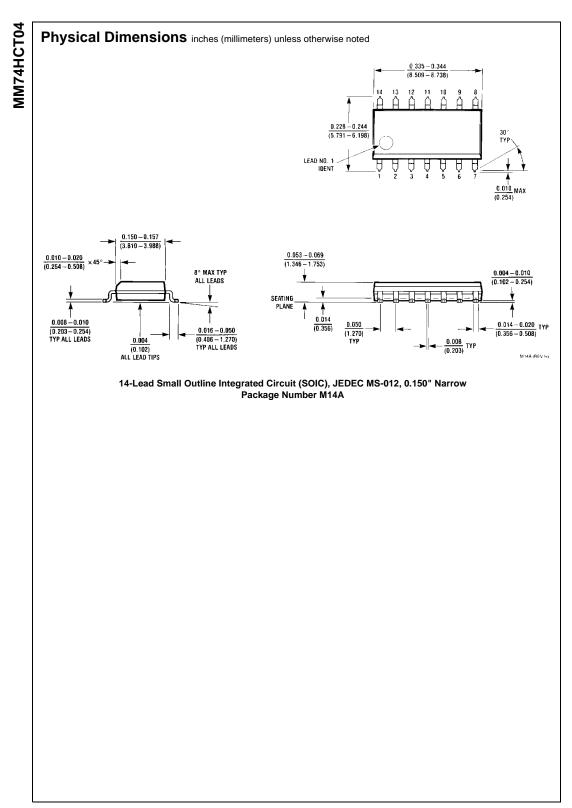
	trical Characteristics				
$V_{CC} = 5.0V, t_r$ Symbol	$= t_f = 6 \text{ ns } C_L = 15 \text{ pF}, T_A = 25^{\circ}\text{C} \text{ (unless parameter}$	ss otherwise noted) Conditions	Тур	Guaranteed Limit	Units
t _{PLH} , t _{PHL}	Maximum Propagation Delay		10	18	ns
^I PLH, ^I PHL	Maximum Propagation Delay		10	18	

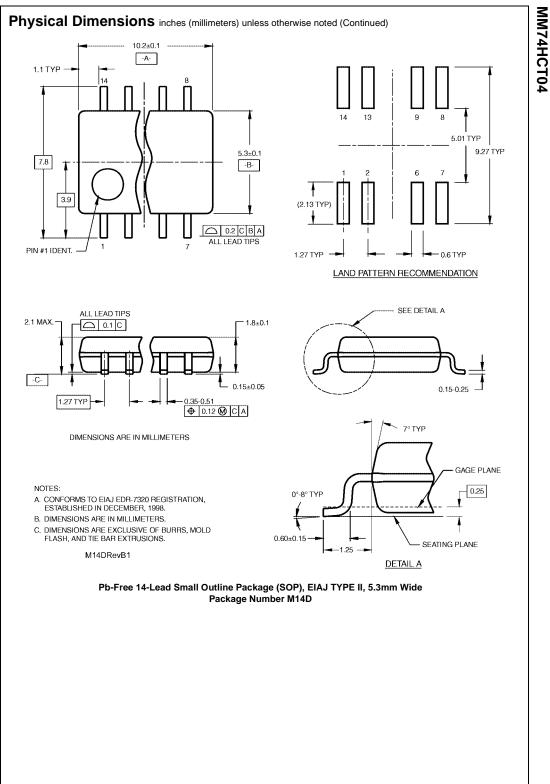
AC Electrical Characteristics

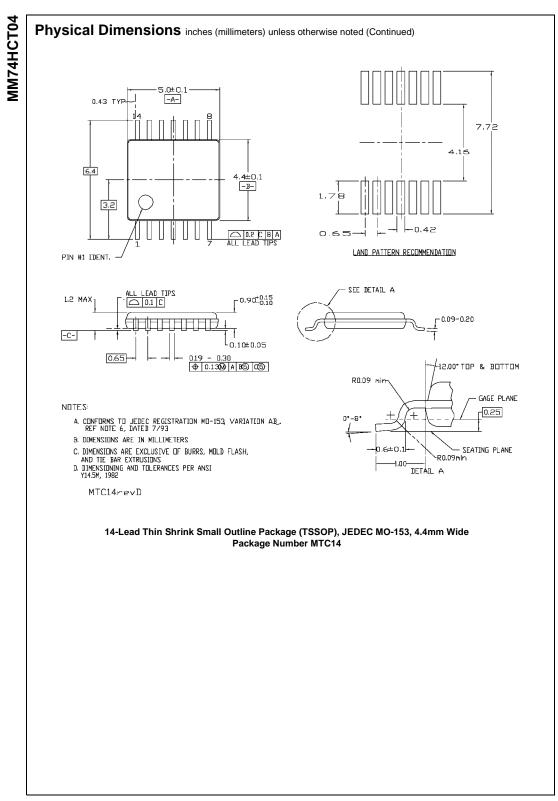
 $V_{CC} = 5.0V \pm 10\%$, $t_r = t_f = 6 \text{ ns}$, $C_L = 50 \text{ pF}$ (unless otherwise noted)

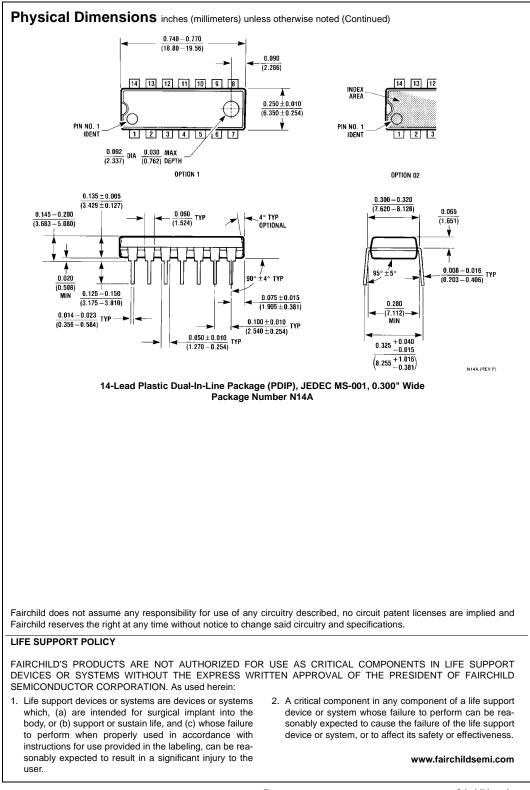
Symbol	Parameter	Conditions	T _A =	25°C	$T_A = -40$ to $85^{\circ}C$	$T_A = -55$ to $125^{\circ}C$	Units	
			Тур		Guaranteed L	imits		
t _{PLH} , t _{PHL}	Maximum Propagation Delay		14	20	25	30	ns	
t _{THL} , t _{TLH}	Maximum Output Rise & Fall Time		8	15	19	22	ns	
CPD	Power Dissipation Capacitance	(Note 5)	20				pF	
CIN	Input Capacitance		5	10	10	10	pF	

Note 5: C_{PD} determines the no load dynamic power consumption, $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$, and the no load dynamic current consumption, $I_S = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$, and the no load dynamic current consumption, $I_S = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.









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